THE DATASHEET OF

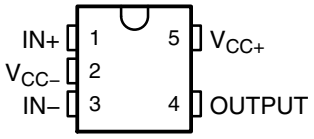
LPV321IDCKRG4

LPV321 SINGLE, LPV358 DUAL, LPV324 QUAD GENERAL-PURPOSE, LOW-VOLTAGE, LOW-POWER, RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS

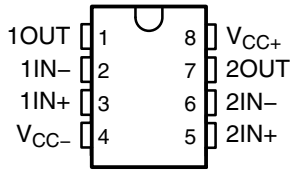
SLOS433I – FEBRUARY 2004 – REVISED MARCH 2005

- 2.7-V and 5-V Performance
- –40°C to 125°C Specification at 5 V
- No Crossover Distortion
- Gain Bandwith of 152 kHz
- Low Supply Current
  - LPV321 . . . 9 μA
  - LPV358 . . . 15 μA
  - LPV324 . . . 28 μA
- Rail-to-Rail Output Swing at 100-kΩ Load
  - V_{CC+} – 3.5 mV
  - V_{CC-} + 90 mV
- V_{ICR} . . . –0.2 V to V_{CC+} – 0.8 V
- Stable With Capacitive Load of 1000 pF
- Applications
  - Active Filters
  - General-Purpose, Low-Voltage Applications
  - Low-Power and/or Portable Applications
- Latch-Up Performance Exceeds 100 mA per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

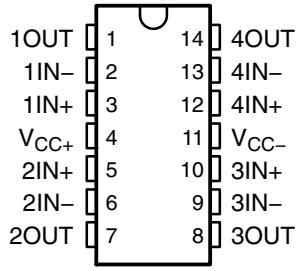
LPV321 . . . DBV OR DCK PACKAGE
(TOP VIEW)



LPV358 . . . D, DDU, OR DGK PACKAGE
(TOP VIEW)



LPV324 . . . D OR PW PACKAGE
(TOP VIEW)



description/ordering information

The LPV321/358/324 devices are low-power (9 μA per channel at 5 V) versions of the LMV321/358/324 operational amplifiers. These are additions to the LMV321/358/324 family of commodity operational amplifiers.

The LPV321/358/324 devices are the most cost-effective solutions for applications where low voltage, low-power operation, space saving, and low price are needed. These devices have rail-to-rail output-swing capability, and the input common-mode voltage range includes ground. They all exhibit excellent speed-power ratios, achieving 152 kHz of bandwidth, with a supply current of only 9 μA typical.

The LPV321, LPV358, and LPV324 are characterized for operation from –40°C to 85°C. The LPV321I, LPV358I, and LPV324I are characterized for operation from –40°C to 125°C.

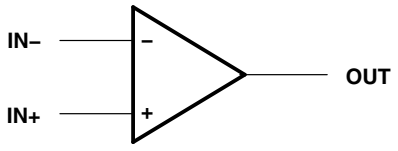
description/ordering information (continued)

ORDERING INFORMATION

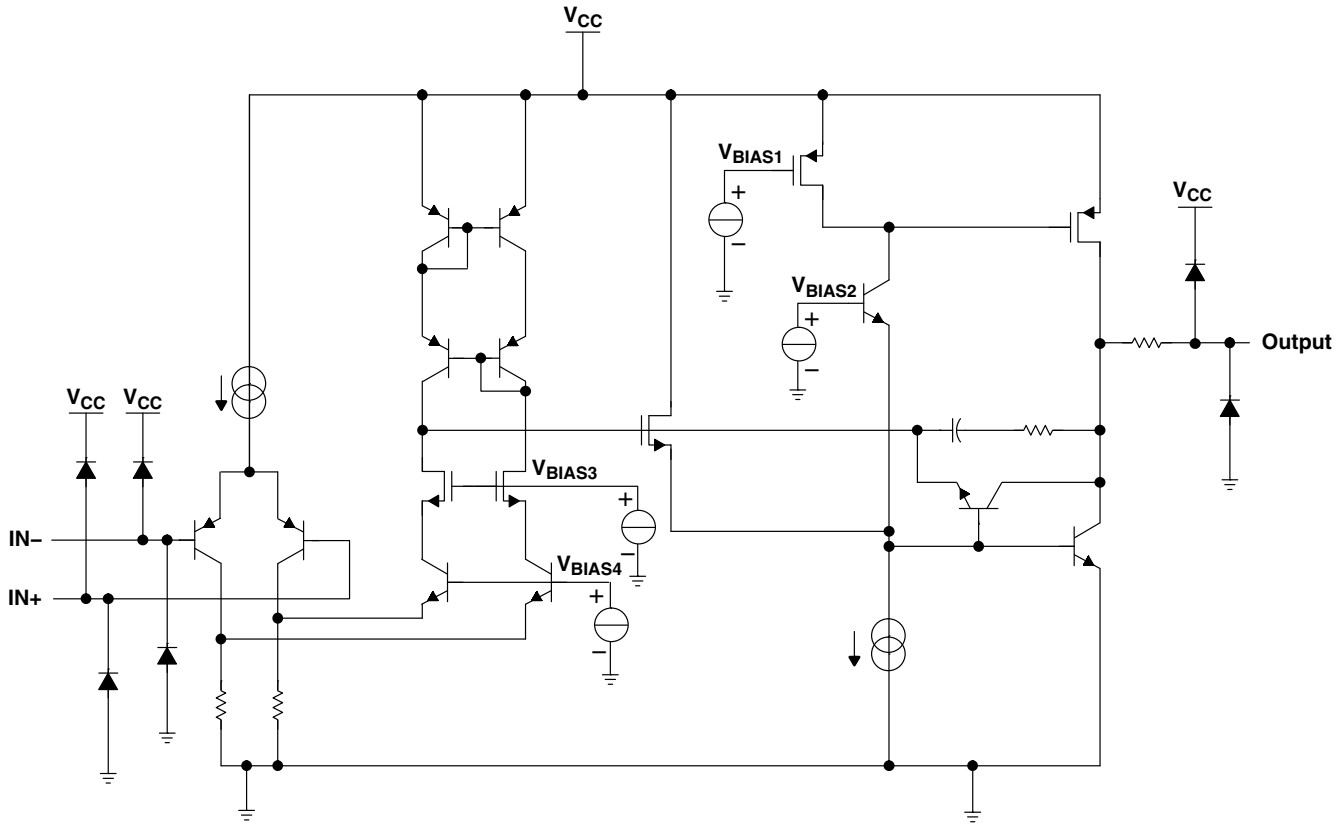
T_A	PACKAGE†			ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	Single	SOT23-5 (DBV)	Reel of 3000	LPV321DBVR	5C7_
			Reel of 250	LPV321DBVT	PREVIEW
		SC-70 (DCK)	Reel of 3000	LPV321DCKR	52_
			Reel of 250	LPV321DCKT	PREVIEW
	Dual	SOIC-8 (D)	Tube of 75	LPV358D	PV358
			Reel of 2500	LPV358DR	
		VSSOP-8 (DDU)	Reel of 3000	LPV358DDUR	5A56
		VSSOP-8 (DGK)	Reel of 2500	LPV358DGKR	546
			Reel of 250	LPV358DGKT	PREVIEW
	Quad	SOIC-14 (D)	Tube of 50	LPV324D	LPV324
			Reel of 2500	LPV324DR	
		TSSOP-14 (PW)	Tube of 90	LPV324PW	PV324
			Reel of 2000	LPV324PWR	
–40°C to 125°C	Single	SOT23-5 (DBV)	Reel of 3000	LPV321IDBVR	5C1_
			Reel of 250	LPV321IDBVT	PREVIEW
		SC-70 (DCK)	Reel of 3000	LPV321IDCKR	53_
			Reel of 250	LPV321IDCKT	PREVIEW
	Dual	SOIC-8 (D)	Tube of 75	LPV358ID	PV358I
			Reel of 2500	LPV358IDR	
		VSSOP-8 (DDU)	Reel of 3000	LPV358IDDUR	5AE6
		VSSOP-8 (DGK)	Reel of 2500	LPV358IDGKR	556
			Reel of 250	LPV358IDGKT	PREVIEW
	Quad	SOIC-14 (D)	Tube of 50	LPV324ID	LPV324I
			Reel of 2500	LPV324IDR	
		TSSOP-14 (PW)	Tube of 90	LPV324IPW	PV324I
			Reel of 2000	LPV324IPWR	

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
‡ DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site.

symbol (each amplifier)



LPV324 simplified schematic



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, $V_{CC+} - V_{CC-}$ (see Note 1)	5.5 V
Differential input voltage, V_{ID} (see Note 2)	$\pm V_{CC}$
Input voltage range, V_I (either input)	V_{CC-} to $V_{CC+} - 1$ V
Package thermal impedance, θ_{JA} (see Notes 3 and 4): 5-pin DBV package	206°C/W
5-pin DCK package	252°C/W
8-pin D package	97°C/W
8-pin DDU package	TBD°C/W
8-pin DGK package	172°C/W
14-pin D package	86°C/W
14-pin PW package	113°C/W
Maximum junction temperature, T_J	150°C
Storage temperature range, T_{stg}	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES:
1. All voltage values, except differential voltages and V_{CC} specified for the measurement of I_{OS}, are with respect to the network GND.
2. Differential voltages are at IN+ with respect to IN–.
3. Maximum power dissipation is a function of $T_J(max)$, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Selecting the maximum of 150°C can affect reliability.
4. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

			MIN	MAX	UNIT
V_{CC}	Supply voltage		2.7	5	V
T_A	Operating free-air temperature	LPV3xx	–40	85	°C
		LPV3xxI	–40	125	

ESD protection

TEST CONDITIONS	TYP	UNIT
Human-Body Model	2	kV
Machine model	200	V
Charged-Device Model	1	kV

2.7-V electrical characteristics

T_A = 25°C, V_{CC+} = 2.7 V, V_{CC-} = 0 V, V_{IC} = 1 V, V_O = V_{CC+}/2, and R_L > 1 MΩ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V_{IO}	Input offset voltage				1.2	7	mV
α_{VIO}	Average temperature coefficient of input offset voltage				4		μV/°C
I_{IB}	Input bias current				1.7	50	nA
I_{IO}	Input offset current				0.6	40	nA
CMRR	Common-mode rejection ratio	0 ≤ V_{IC} ≤ 1.7 V		50	70		dB
k_{SVR}	Supply-voltage rejection ratio	2.7 V ≤ V_{CC+} ≤ 5 V, V_{IC} = 1 V, V_O = 1 V		50	65		dB
V_{ICR}	Common-mode input voltage range	CMRR ≥ 50 dB		0 to 1.7	–0.2 to 1.9		V
V_O	Output swing	R_L = 100 kΩ to 1.35 V	High level	V_{CC+} – 0.100	V_{CC+} – 0.003		V
			Low level		0.080	0.180	
I_{CC}	Supply current	LPV321			4	8	μA
		LPV358 (both amplifiers)			8	16	
		LPV324 (all four amplifiers)			16	24	
SR	Slew rate‡				0.1		V/μs
GBW	Gain bandwidth product	C_L = 22 pF (see Note 5)			205		kHz
Φ_m	Phase margin	C_L = 22 pF (see Note 5)			71		deg
	Gain margin	C_L = 22 pF (see Note 5)			11		dB
V_n	Equivalent input noise voltage	f = 1 kHz			178		nV/√Hz
I_n	Equivalent input noise current	f = 1 kHz			0.5		pA/√Hz

† All typical values are at V_{CC} = 2.7 V, T_A = 25°C.
‡ Number specified is the slower of the positive and negative slew rates.
NOTE 5: Closed-loop gain = 18 dB, V_{IC} = V_{CC+}/2

5-V electrical characteristics

T_A = 25°C, V_{CC+} = 5 V, V_{CC-} = 0 V, V_{IC} = 2 V, V_O = V_{CC+}/2, and R_L > 1 MΩ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A	MIN	TYP†	MAX	UNIT
V_{IO}	Input offset voltage			25°C		1.5	7	mV
				–40°C to 85°C			10	
				–40°C to 125°C			11	
α_{VIO}	Average temperature coefficient of input offset voltage			25°C		4		µV/°C
I_{IB}	Input bias current			25°C		2	50	nA
				–40°C to 85°C			60	
				–40°C to 125°C			65	
CMRR	Common-mode rejection ratio	0 ≤ V_{IC} ≤ 4 V		25°C	50	71		dB
k_{SVR}	Supply-voltage rejection ratio	2.7 V ≤ V_{CC+} ≤ 5 V, V_{IC} = 1 V, V_O = 1 V		25°C	50	65		dB
V_{ICR}	Common-mode input voltage range	CMRR ≥ 50 dB		25°C	0 to 4	–0.2 to 4.2		V
I_{IO}	Input offset current			25°C		0.6	40	nA
				–40°C to 85°C			50	
				–40°C to 125°C			55	
V_O	Output swing	R_L = 100 kΩ to 2.5 V	High level	25°C	V_{CC+} – 0.100	V_{CC+} – 0.0035		V
				–40°C to 85°C	V_{CC+} – 0.200			
				–40°C to 125°C	V_{CC+} – 0.225			
			Low level	25°C		0.090	0.180	
				–40°C to 85°C			0.220	
				–40°C to 125°C			0.240	
I_{OS}	Output short-circuit current	Sourcing, V_O = 0 V		25°C	2	17		mA
		Sinking, V_O = 5 V			20	72		
I_{CC}	Supply current	LPV321		25°C		9	12	µA
				–40°C to 85°C			15	
				–40°C to 125°C			40	
		LPV358 (both amplifiers)		25°C		15	20	
				–40°C to 85°C			24	
				–40°C to 125°C			80	
		LPV324 (all four amplifiers)		25°C		28	42	
				–40°C to 85°C			46	
				–40°C to 125°C			125	
A_V‡	Large-signal voltage gain	R_L = 100 kΩ		25°C	15	100		V/mV
				–40°C to 85°C	10			
				–40°C to 125°C	10			
SR§	Slew rate			25°C		0.1		V/µs

† All typical values are at V_{CC} = 5 V, T_A = 25°C.
‡ R_L is connected to V_{CC-}. The output voltage is 0.5 V ≤ V_O ≤ 4.5 V.
§ Number specified is the slower of the positive and negative slew rates. Connected as a voltage follower with 3-V step input.

5-V electrical characteristics
T_A = 25°C, V_{CC+} = 5 V, V_{CC-} = 0 V, V_{IC} = 2 V, V_O = V_{CC+}/2, and R_L > 1 MΩ (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS	T_A	MIN	TYP†	MAX	UNIT
GBW	Gain bandwidth product	C_L = 22 pF (see Note 5)	25°C		237		kHz
Φ_m	Phase margin	C_L = 22 pF (see Note 5)	25°C		74		deg
	Gain margin	C_L = 22 pF (see Note 5)	25°C		12		dB
V_n	Equivalent input noise voltage	f = 1 kHz	25°C		146		nV/√Hz
I_n	Equivalent input noise current	f = 1 kHz	25°C		0.3		pA/√Hz

† All typical values are at V_{CC} = 5 V, T_A = 25°C.
NOTE 5: Closed-loop gain = 18 dB, V_{IC} = V_{CC+}/2

SUPPLY CURRENT
vs
SUPPLY VOLTAGE
(LPV324 – All Channels)

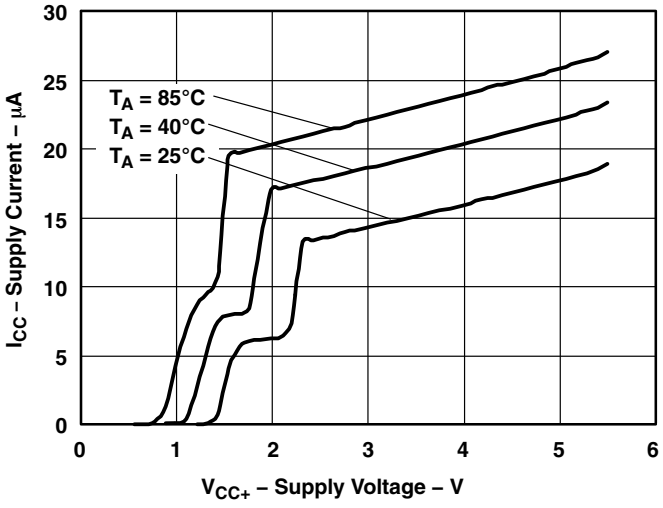


Figure 1

INPUT BIAS CURRENT
vs
TEMPERATURE

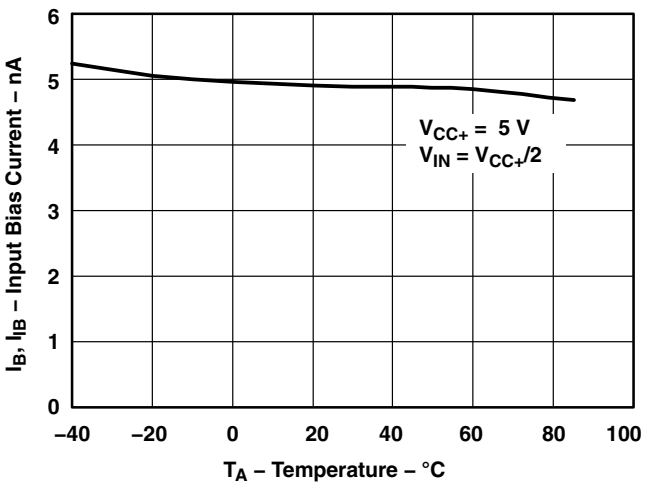


Figure 2

SOURCING CURRENT
vs
OUTPUT VOLTAGE

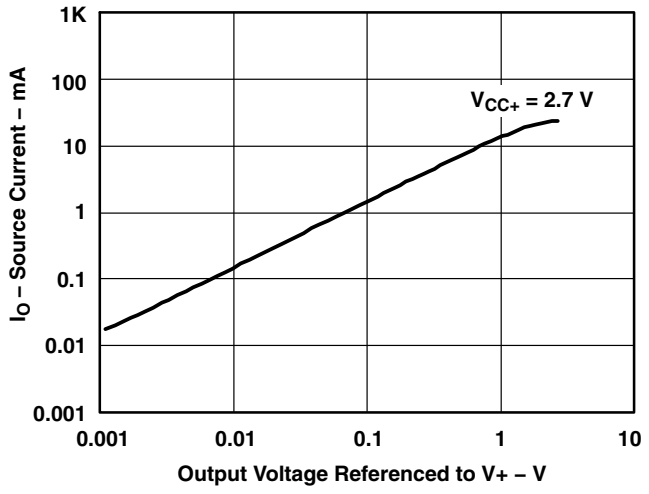


Figure 3

SOURCING CURRENT
vs
OUTPUT VOLTAGE

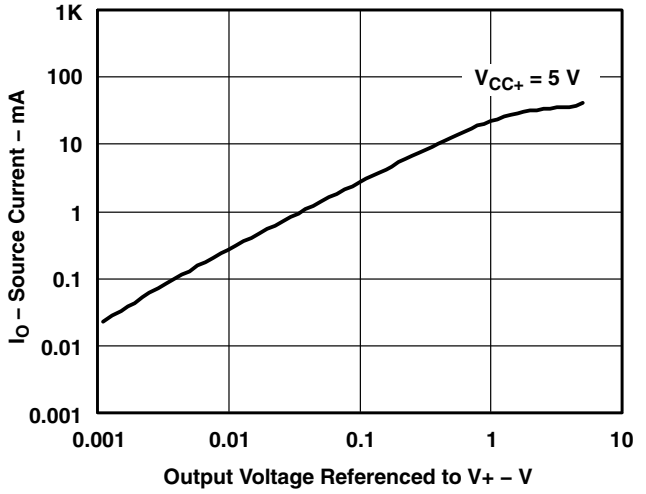


Figure 4

SINKING CURRENT
vs
OUTPUT VOLTAGE

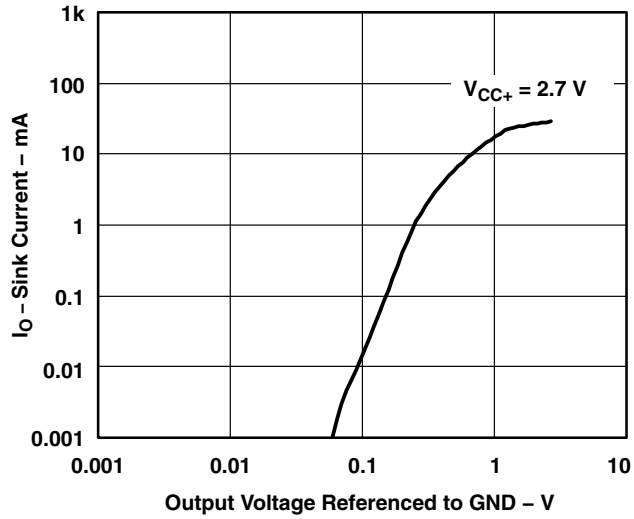


Figure 5

SINKING CURRENT
vs
OUTPUT VOLTAGE

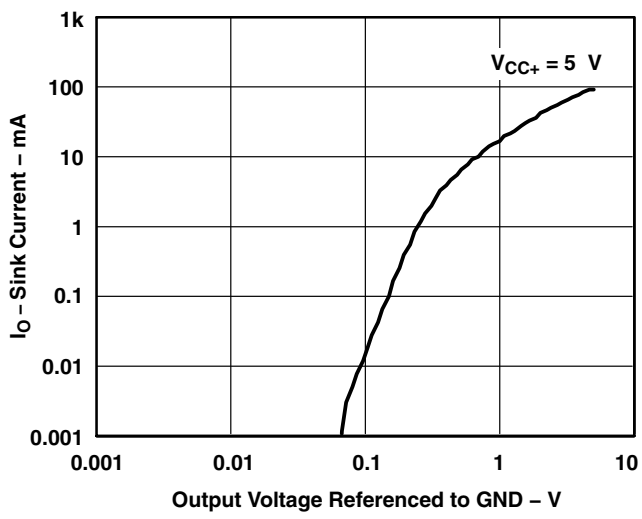


Figure 6

OUTPUT VOLTAGE SWING
vs
SUPPLY VOLTAGE

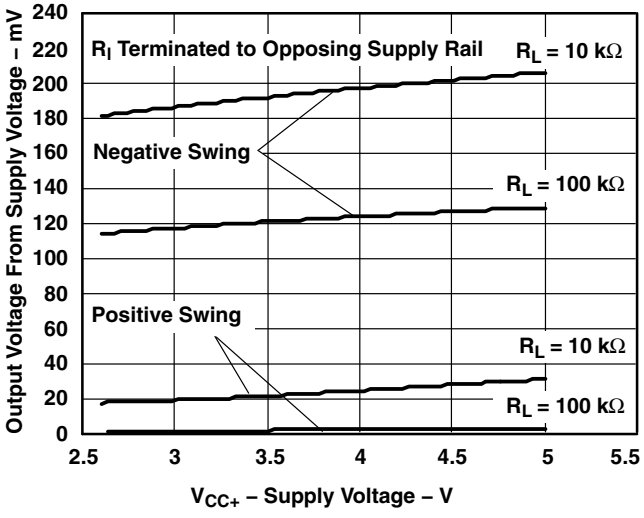


Figure 7

INPUT VOLTAGE NOISE
vs
FREQUENCY

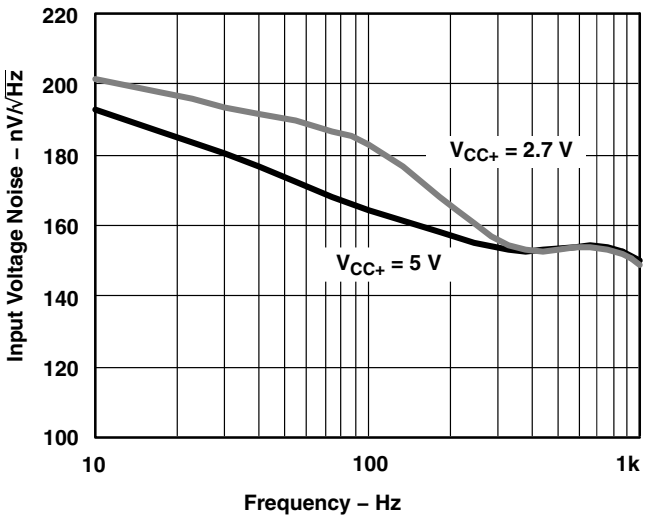


Figure 8

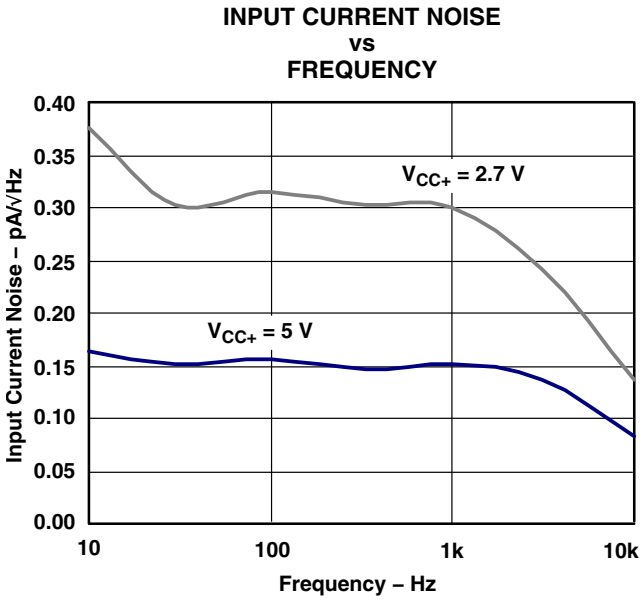


Figure 9

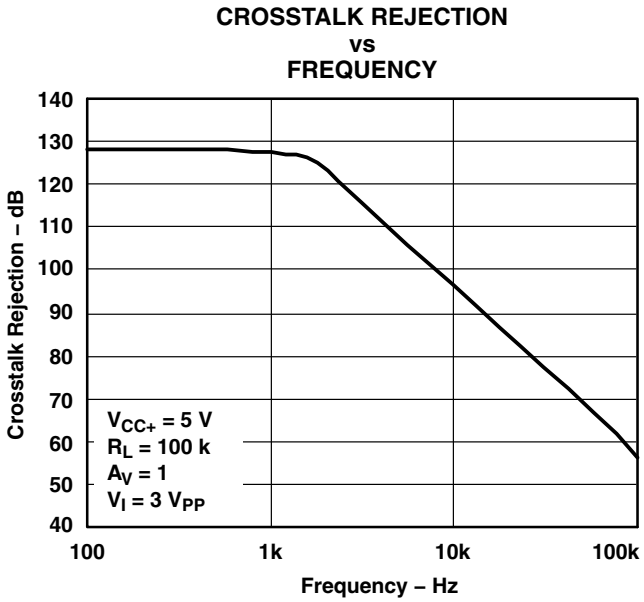


Figure 10

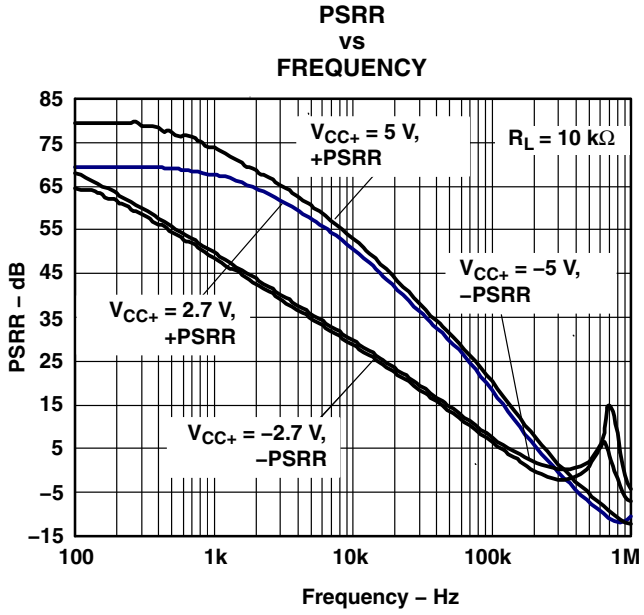


Figure 11

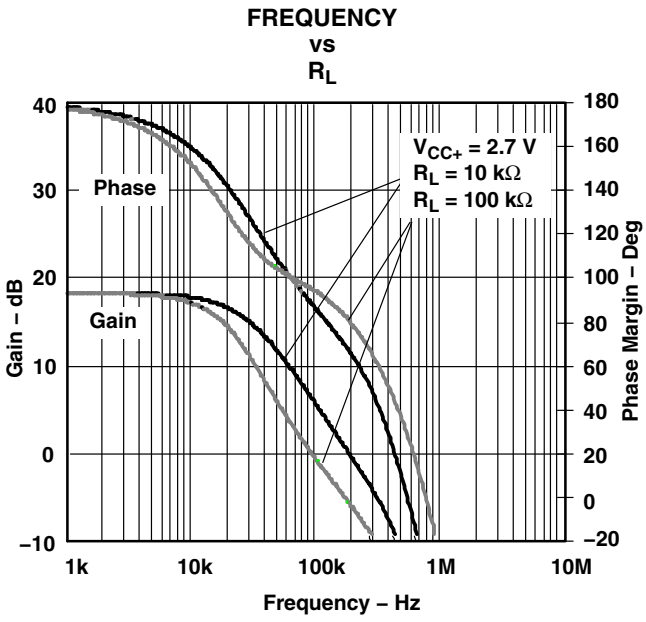


Figure 12

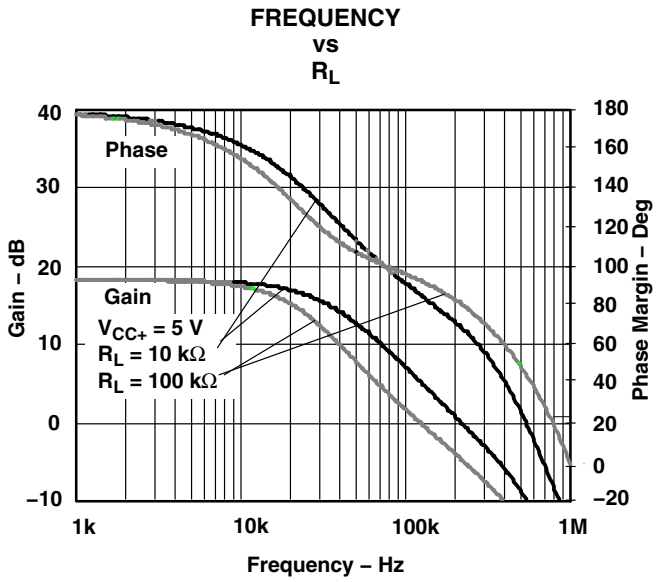


Figure 13

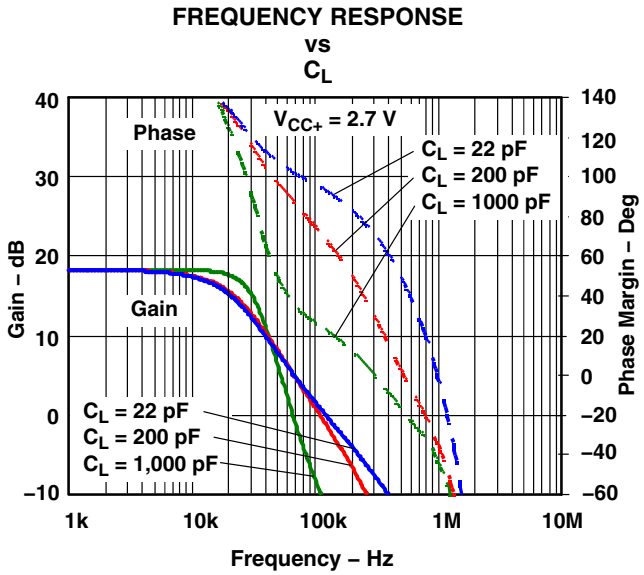


Figure 14

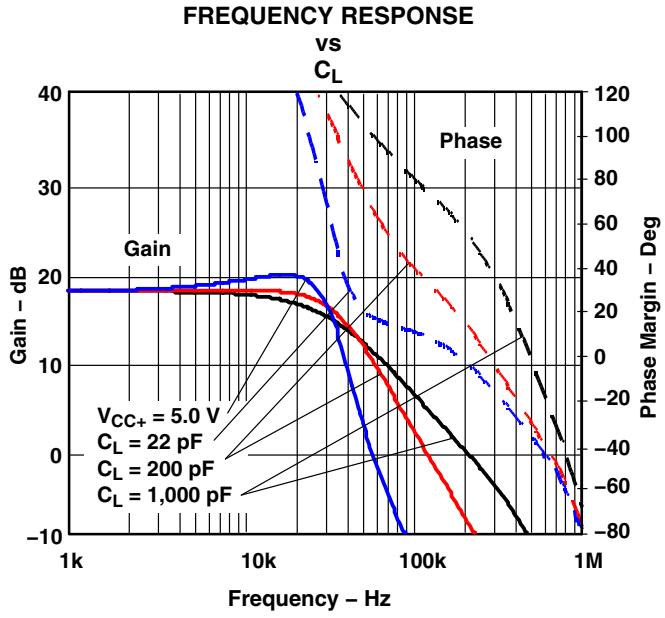


Figure 15

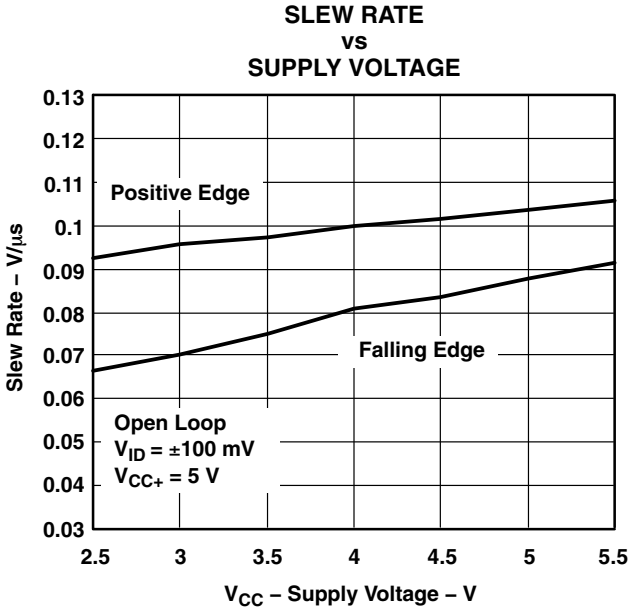


Figure 16

NONINVERTING LARGE-SIGNAL PULSE RESPONSE

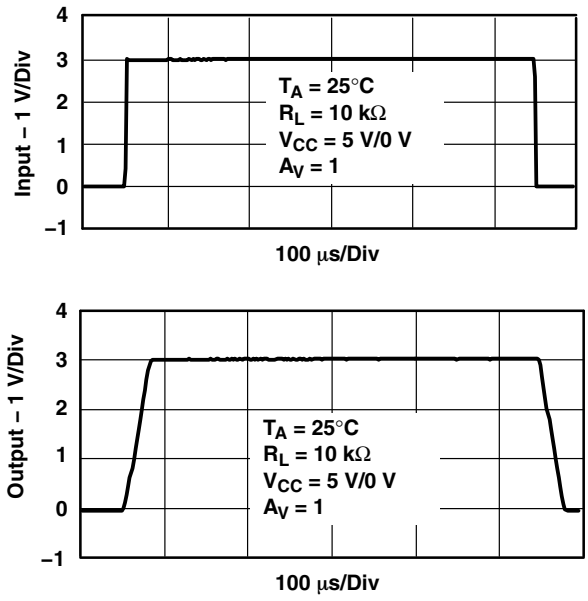


Figure 17

NONINVERTING SMALL-SIGNAL PULSE RESPONSE

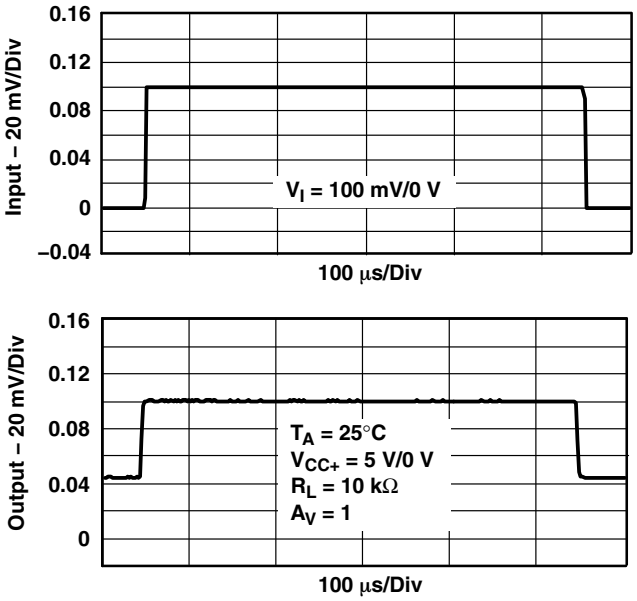


Figure 18

INVERTING LARGE-SIGNAL PULSE RESPONSE

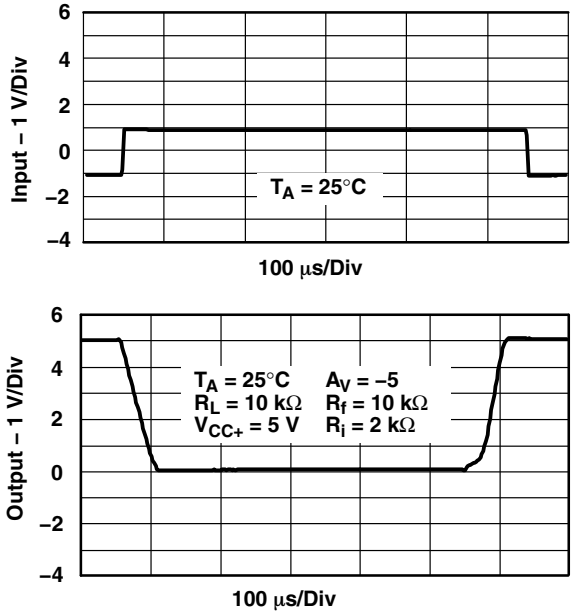


Figure 19

INVERTING SMALL-SIGNAL PULSE RESPONSE

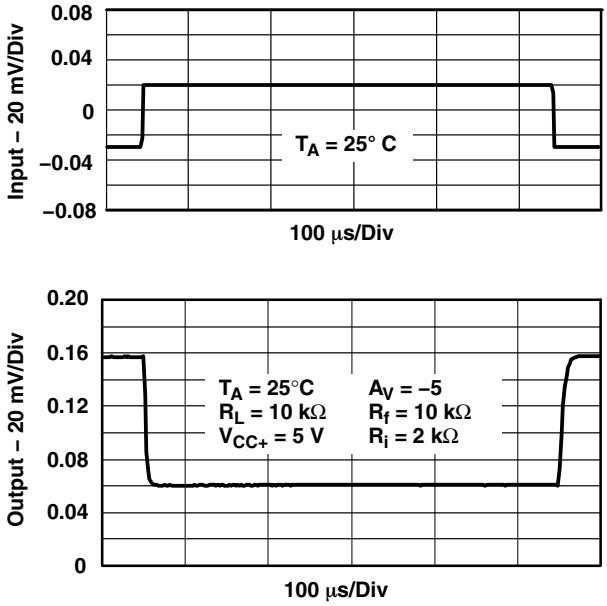


Figure 20

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LPV321DBVR	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI	-40 to 85	(5C7B ~ 5C7I)	
LPV321DBVRE4	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI	-40 to 85		
LPV321DBVRG4	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI	-40 to 85		
LPV321DCKR	OBSOLETE	SC70	DCK	5		TBD	Call TI	Call TI	-40 to 85	(52B ~ 52I)	
LPV321DCKRE4	OBSOLETE	SC70	DCK	5		TBD	Call TI	Call TI	-40 to 85		
LPV321DCKRG4	OBSOLETE	SC70	DCK	5		TBD	Call TI	Call TI	-40 to 85		
LPV321IDBVR	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI	-40 to 125	(5C1B ~ 5C1I)	
LPV321IDBVRE4	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI	-40 to 125		
LPV321IDBVRG4	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI	-40 to 125		
LPV321IDCKR	OBSOLETE	SC70	DCK	5		TBD	Call TI	Call TI	-40 to 125	(53B ~ 53I)	
LPV321IDCKRE4	OBSOLETE	SC70	DCK	5		TBD	Call TI	Call TI	-40 to 125		
LPV321IDCKRG4	OBSOLETE	SC70	DCK	5		TBD	Call TI	Call TI	-40 to 125		
LPV324D	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85	LPV324	
LPV324DE4	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85		
LPV324DG4	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85		
LPV324DR	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85	LPV324	
LPV324DRE4	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85		
LPV324DRG4	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85		
LPV324ID	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 125	LPV324I	
LPV324IDE4	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 125		
LPV324IDG4	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 125		
LPV324IDR	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 125	LPV324I	
LPV324IDRE4	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 125		
LPV324IDRG4	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 125		
LPV324IPW	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 125	PV324I	
LPV324IPWE4	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 125		
LPV324IPWG4	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 125		
LPV324IPWR	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 125	PV324I	
LPV324IPWRE4	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 125		
LPV324IPWRG4	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 125		

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LPV324PW	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85	PV324	
LPV324PWE4	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85		
LPV324PWG4	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85		
LPV324PWR	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85	PV324	
LPV324PWRE4	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85		
LPV324PWRG4	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85		
LPV358D	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85	PV358	
LPV358DDUR	OBSOLETE	VSSOP	DDU	8		TBD	Call TI	Call TI	-40 to 85	5A56	
LPV358DDURE4	OBSOLETE	VSSOP	DDU	8		TBD	Call TI	Call TI	-40 to 85		
LPV358DDURG4	OBSOLETE	VSSOP	DDU	8		TBD	Call TI	Call TI	-40 to 85		
LPV358DE4	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		
LPV358DG4	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		
LPV358DGKR	OBSOLETE	VSSOP	DGK	8		TBD	Call TI	Call TI	-40 to 85	546	
LPV358DGKRG4	OBSOLETE	VSSOP	DGK	8		TBD	Call TI	Call TI	-40 to 85		
LPV358DR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85	PV358	
LPV358DRE4	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		
LPV358DRG4	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		
LPV358ID	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 125	PV358I	
LPV358IDDUR	OBSOLETE	VSSOP	DDU	8		TBD	Call TI	Call TI	-40 to 125	5AE6	
LPV358IDDURE4	OBSOLETE	VSSOP	DDU	8		TBD	Call TI	Call TI	-40 to 125		
LPV358IDDURG4	OBSOLETE	VSSOP	DDU	8		TBD	Call TI	Call TI	-40 to 125		
LPV358IDE4	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 125		
LPV358IDG4	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 125		
LPV358IDGKR	OBSOLETE	VSSOP	DGK	8		TBD	Call TI	Call TI	-40 to 125	556	
LPV358IDGKRG4	OBSOLETE	VSSOP	DGK	8		TBD	Call TI	Call TI	-40 to 125		
LPV358IDR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 125	PV358I	
LPV358IDRE4	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 125		
LPV358IDRG4	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 125		

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

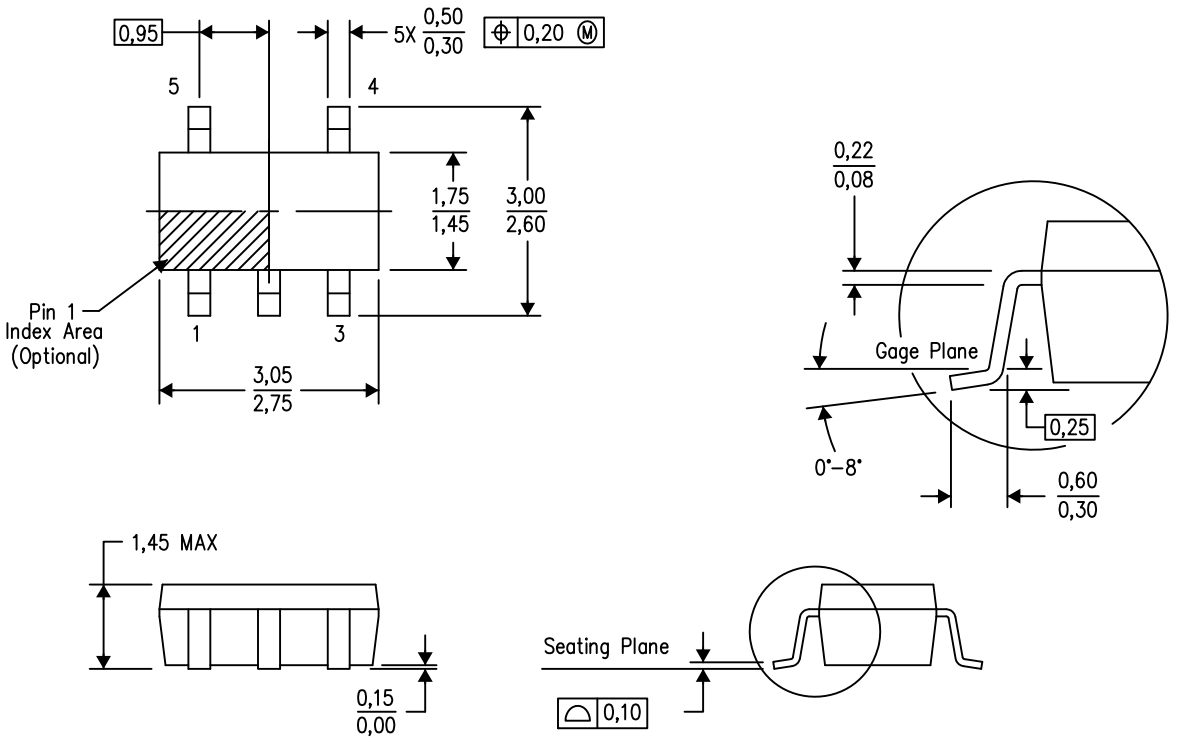
(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

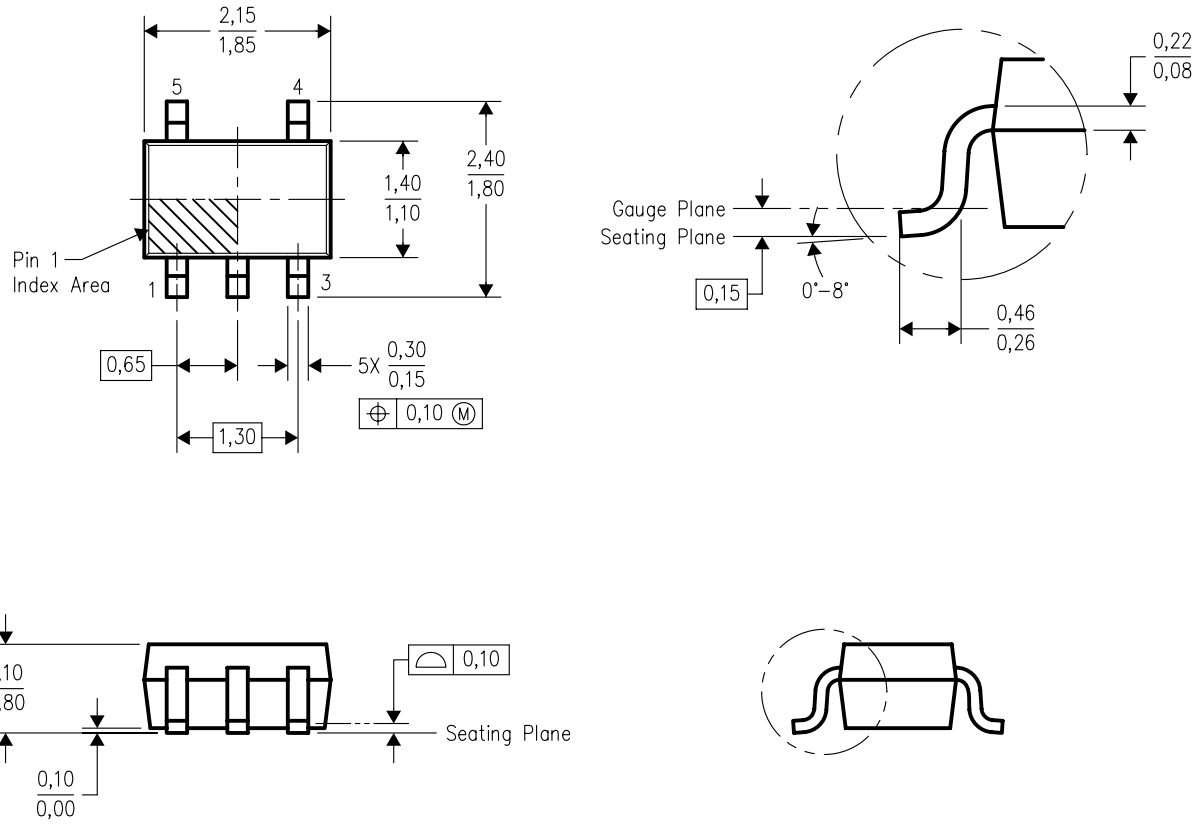
DBV (R–PDSO–G5) PLASTIC SMALL–OUTLINE PACKAGE



4073253–4/N 12/14

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Falls within JEDEC MO–178 Variation AA.

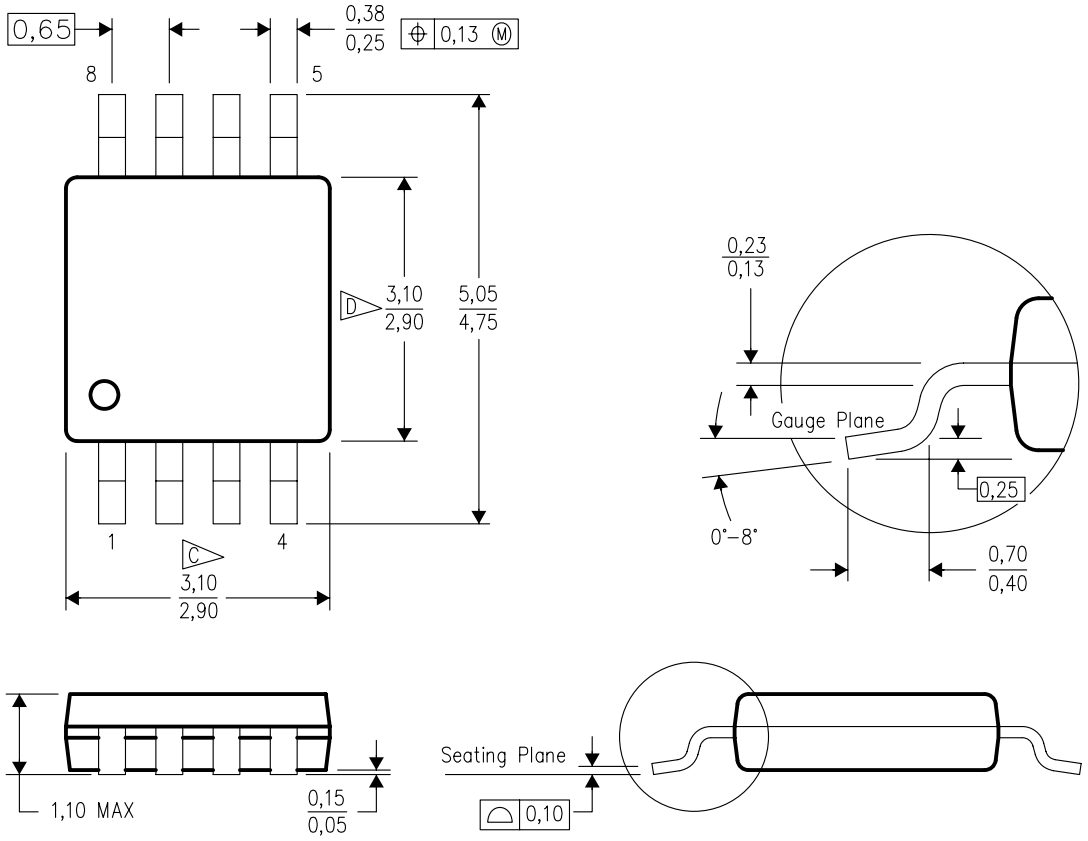
DCK (R–PDSO–G5) PLASTIC SMALL–OUTLINE PACKAGE



4093553–3/G 01/2007

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Falls within JEDEC MO–203 variation AA.

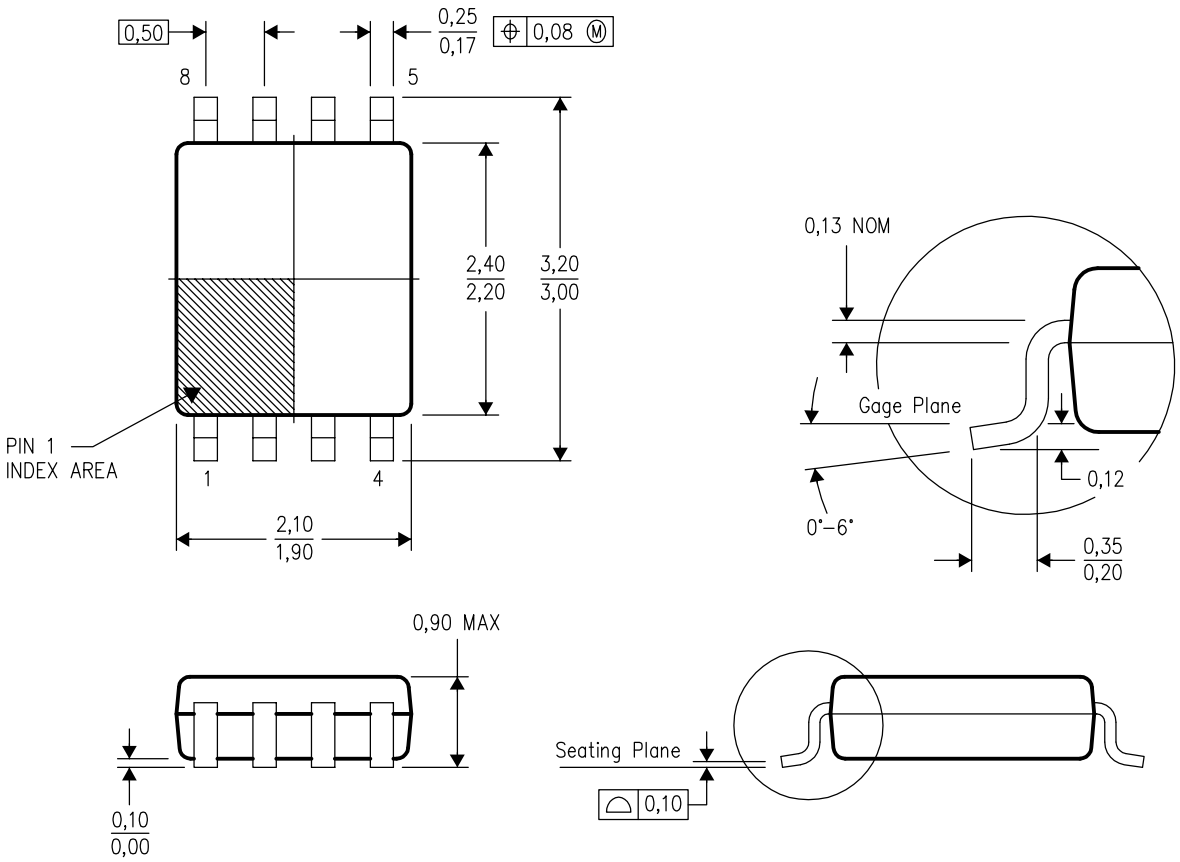
DGK (S–PDSO–G8) PLASTIC SMALL–OUTLINE PACKAGE



4073329/E 05/06

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
E. Falls within JEDEC MO–187 variation AA, except interlead flash.

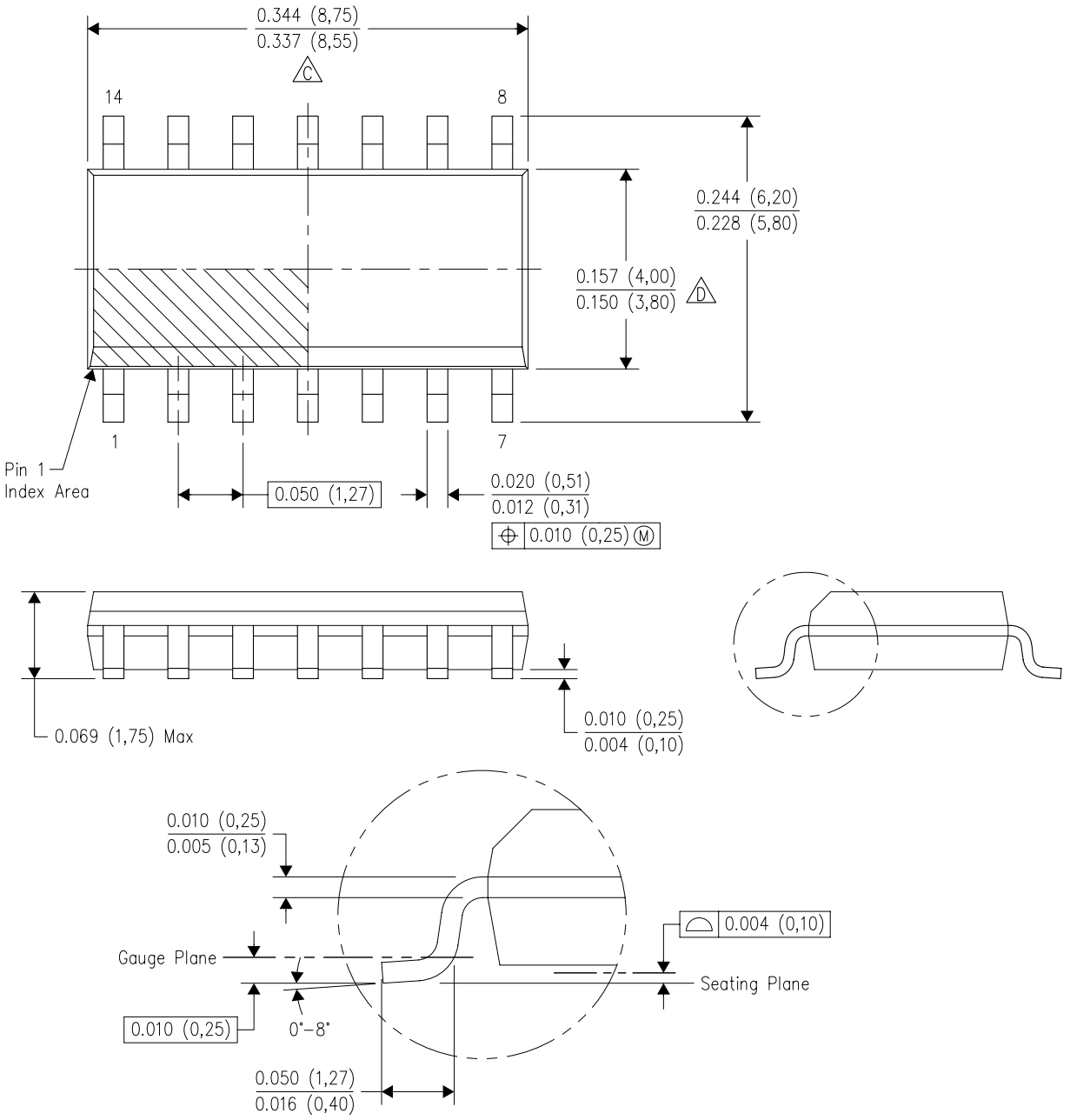
DDU (R–PDSO–G8) PLASTIC SMALL–OUTLINE PACKAGE



4205140/A 05/03

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion.
D. Falls within JEDEC MO–187 variation CA.

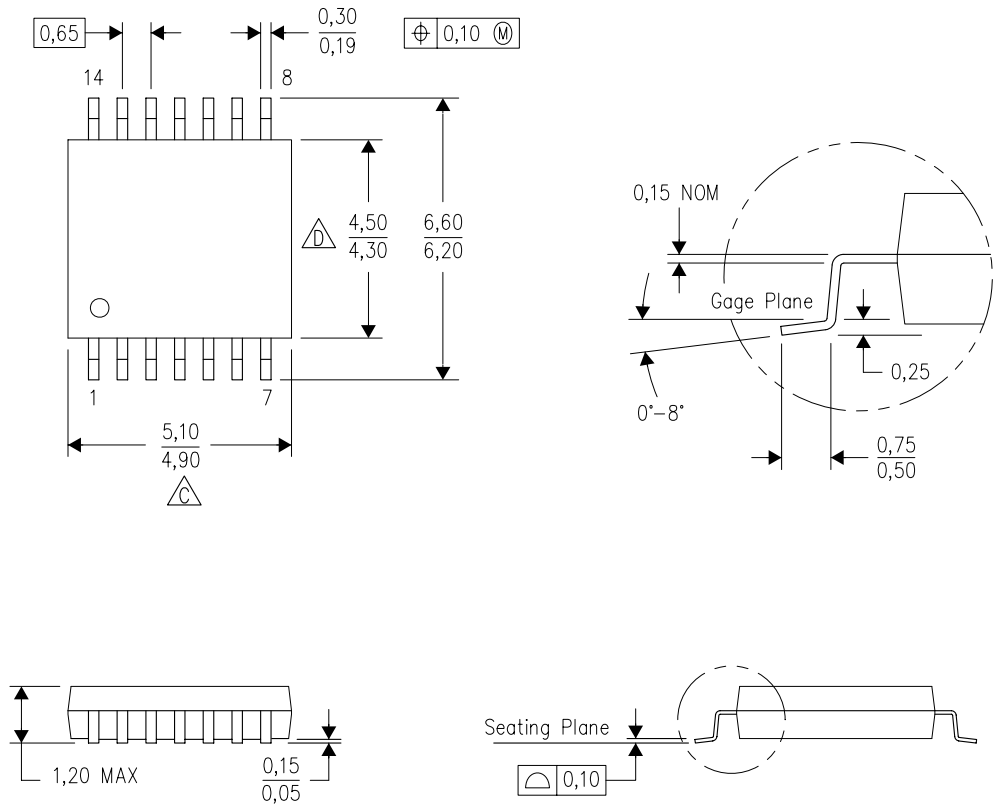
D (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040047–5/M 06/11

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AB.

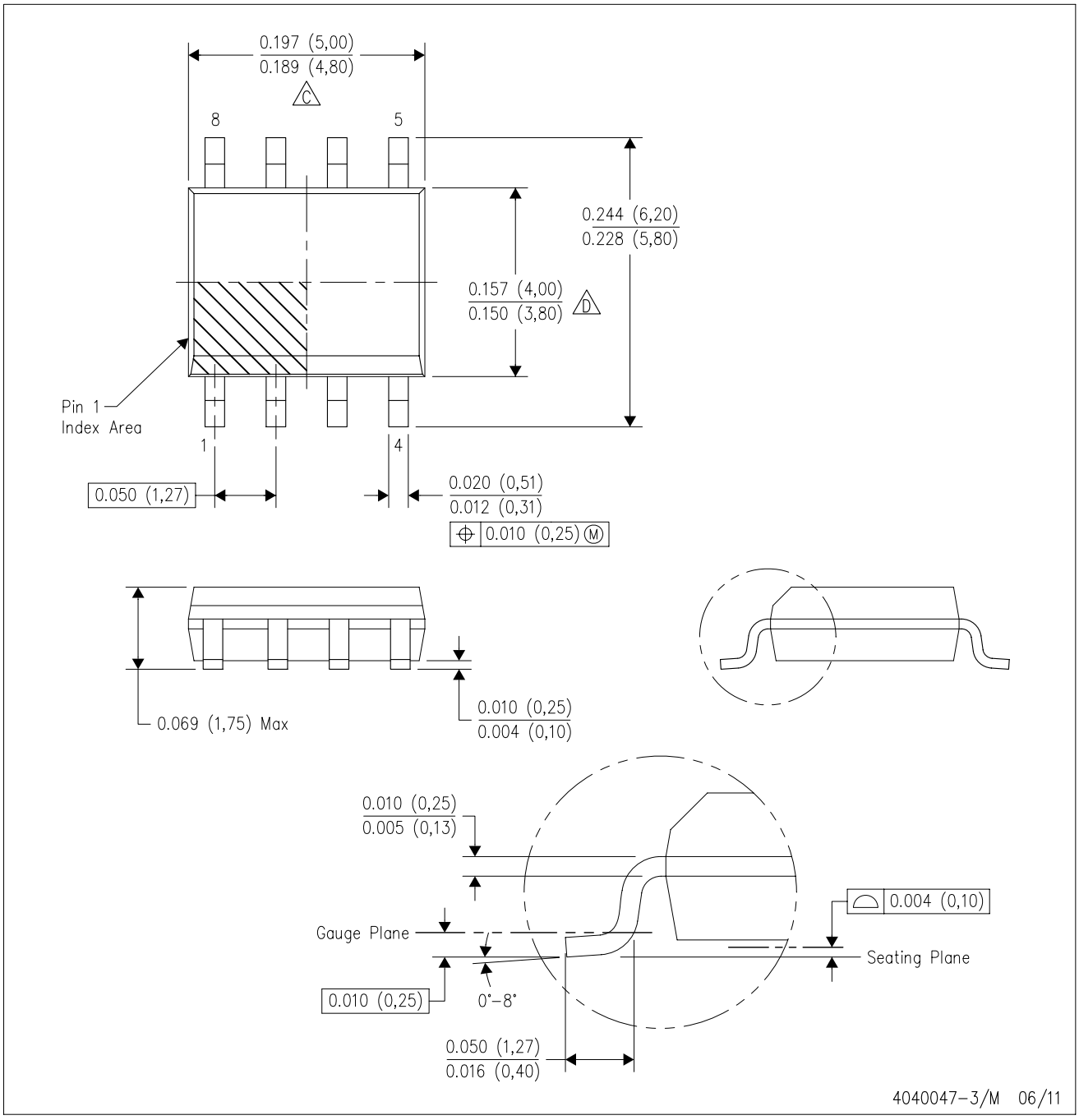
PW (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040064–3/G 02/11

NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
E. Falls within JEDEC MO–153

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AA.

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